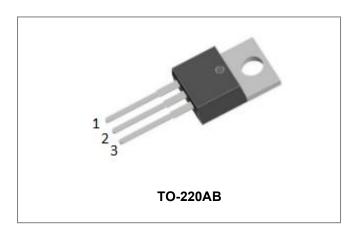






# **MBR40200CT SCHOTTKY RECTIFIER**



#### **Features**

- 150°C T<sub>J</sub> operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced
- mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Terminals finish: Tin Lead-free plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### **Circuit Diagram**



### **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	200	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	Tc=114°C, In DC	20(Per Leg) 40(Per Device)	Α
Peak Repetitive Forward Current(Per Leg)	I <sub>FRM</sub>	Rated V <sub>R</sub> square wave, 20KHz T <sub>C</sub> =133°C	20	Α
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I <sub>FSM</sub>	8.3ms, Half Sine pulse, T <sub>C</sub> = 25 °C	396	Α

### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	V <sub>F1</sub>	@ 20A, Pulse, T <sub>J</sub> = 25 °C	0.85	0.90	V
	V <sub>F2</sub>	@ 20A, Pulse, T <sub>J</sub> = 125 °C	0.72	0.80	V
Reverse Current(Per Leg)*	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 25 °C	0.0001	1.0	mA
	I <sub>R2</sub>	$@V_R = \text{rated } V_R, T_J = 125  ^{\circ}\text{C}$	0.1	11	mA
Junction Capacitance(Per Leg)	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	300	450	pF

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

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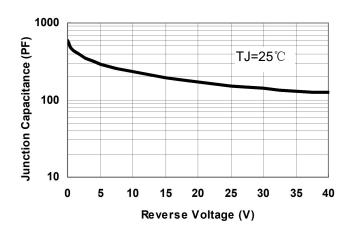




## **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R <sub>0</sub> JC	DC operation	2.0	°C/W
Typical Thermal Resistance Junction to Ambient	$R_{\theta JA}$	DC operation	50	°C/W
Typical Thermal Resistance, Case to Heat Sink	R <sub>θJS</sub>	Mounting surface, smooth and greased	0.50	°C/W
Approximate Weight	wt	-	2	g

#### **Ratings and Characteristics Curves**



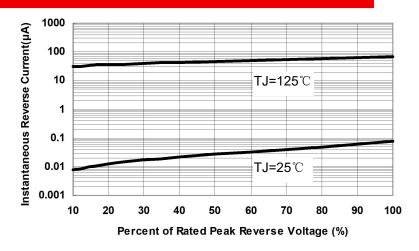


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

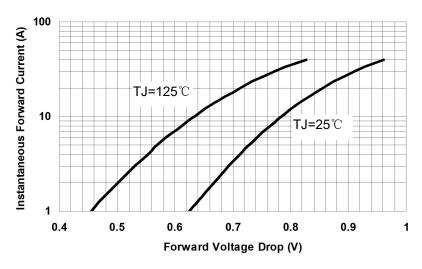


Fig.3-Typical Instantaneous Forward Voltage Characteristics

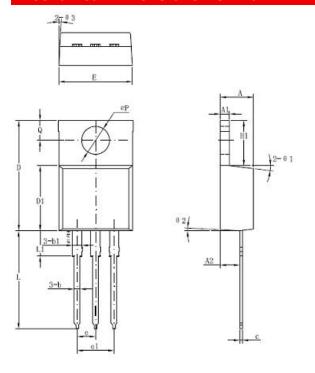
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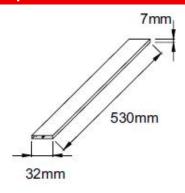


### **Mechanical Dimensions TO-220AB**



Symbol	Dimensions in millimeters				
	Min	Typical	Max		
Α	3.56	-	4.83		
A1	0.51	-	1.4		
A2	2.03	-	2.92		
b	0.38	-	1.02		
b1	1.14	-	1.78		
С	0.31	-	0.61		
D	14.22	-	16.51		
D1	8.38	-	9.42		
E	9.65	-	10.67		
е	-	2.54	-		
e1	-	5.08	-		
H1	5.84	-	6.86		
L	12.7	-	14.73		
L1	-	-	6.35		
ФР	-	3.56	-		
Q	2.54	-	3.43		

## **Tube Specification**



## **Marking Diagram**



Where XXXXX is YYWWL

MBR = Device Type 40 = Forward Current (40A) 200 = Reverse Voltage(200V) CT = Configuration

SSG = SSG
YY = Year
WW = Week
L = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

## **Ordering Information**

Device	Package	Shipping	
MBR40200CT	TO-220AB (Pb-Free)	50 pcs/ tube	

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